

# NX3P2902B

## Logic controlled high-side power switch

Rev. 2 — 22 February 2018

Product data sheet

### 1. General description

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The NX3P2902B is a high-side load switch which features a low ON resistance P-channel MOSFET. The MOSFET supports more than 500 mA of continuous current and an integrated output discharge resistor to discharge the output capacitance when disabled. Designed for operation from 1.1 V to 3.6 V, it is used in power domain isolation applications to reduce power dissipation and extend battery life. The enable logic includes integrated logic level translation making the device compatible with lower voltage processors and controllers. The NX3P2902B is ideal for portable, battery operated applications due to low ground current and OFF-state current.

### 2. Features and benefits

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- Wide supply voltage range from 1.1 V to 3.6 V
- Very low ON resistance:
  - ◆ 95 mΩ at a supply voltage of 1.8 V
- High noise immunity
- Low OFF-state leakage current (600 nA maximum)
- 1.2 V control logic at a supply voltage of 3.6 V
- High current handling capability (500 mA continuous current)
- Internal output discharge resistor
- Turn-on slew rate limiting
- ESD protection:
  - ◆ HBM JESD22-A114F Class 3A exceeds 4000 V
  - ◆ CDM AEC-Q100-011 revision B exceeds 500 V
- Specified from -40 °C to +85 °C

### 3. Applications

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- Cell phone
- Digital cameras and audio devices
- Portable and battery-powered equipment



## 4. Ordering information

Table 1. Ordering information

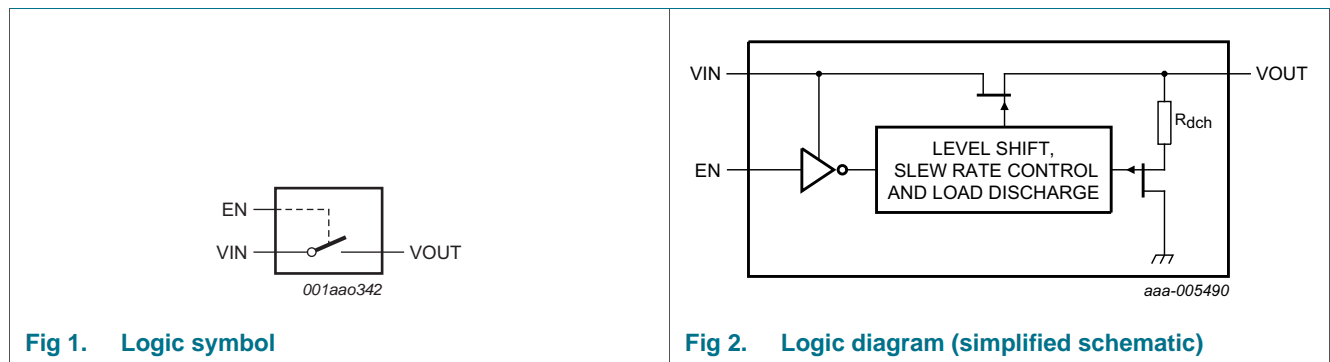
Type number	Topside marking	Package		
		Name	Description	Version
NX3P2902BUK	x2	WLCSP4	wafer level chip-scale package; 4 bumps; 0.77 × 0.77 × 0.51 mm. (Backside coating included)	NX3P2902B

### 4.1 Ordering options

Table 2. Ordering options

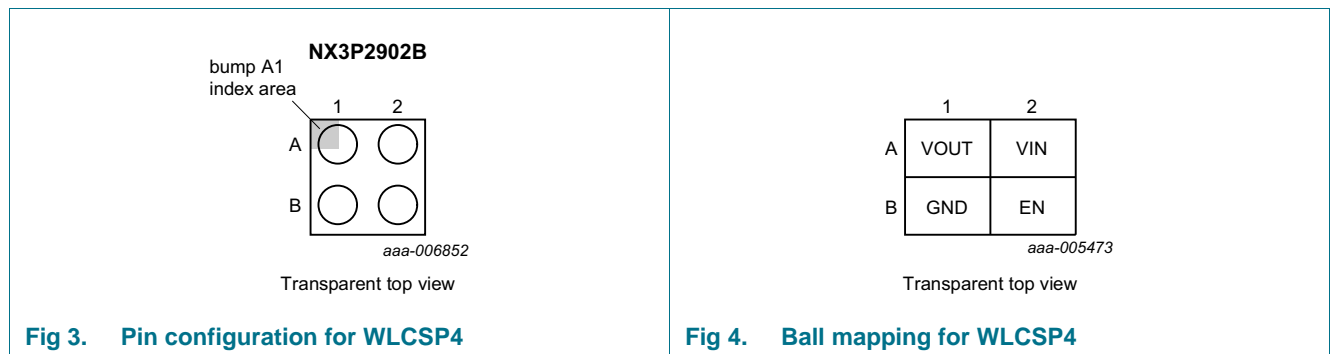
Type number	Orderable part number	Package	Packing method	Minimum order quantity	Temperature
NX3P2902BUK	NX3P2902BUKZ	WLCSP4	Reel 7" Q1/T1 in Drypack	3000	T <sub>amb</sub> = -40 °C to +85 °C

## 5. Functional diagram



## 6. Pinning information

### 6.1 Pinning



## 6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
VOUT	A1	output voltage
GND	B1	ground (0 V)
VIN	A2	input voltage
EN	B2	enable input (active HIGH)

## 7. Functional description

Table 4. Function table<sup>[1]</sup>

Input EN	Switch
L	switch OFF
H	switch ON

[1] H = HIGH voltage level; L = LOW voltage level.

## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>I</sub>	input voltage	input EN <sup>[1]</sup>	-0.5	+4.0	V
		input VIN <sup>[2]</sup>	-0.5	+4.0	V
V <sub>SW</sub>	switch voltage	output VOUT <sup>[2]</sup>	-0.5	V <sub>I(VIN)</sub>	V
I <sub>IK</sub>	input clamping current	input EN: V <sub>I(EN)</sub> < -0.5 V	-50	-	mA
I <sub>SK</sub>	switch clamping current	input VIN: V <sub>I(VIN)</sub> < -0.5 V	-50	-	mA
		output VOUT: V <sub>O(VOUT)</sub> < -0.5 V	-50	-	mA
		output VOUT: V <sub>O(VOUT)</sub> > V <sub>I(VIN)</sub> + 0.5 V	-	50	mA
I <sub>SW</sub>	switch current	V <sub>SW</sub> > -0.5 V			
		T <sub>amb</sub> = 25 °C	-	±1000	mA
		T <sub>amb</sub> = 85 °C	-	±500	mA
T <sub>j(max)</sub>	maximum junction temperature		-40	+125	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	<sup>[3]</sup>	-	300	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed.

[3] The (absolute) maximum power dissipation depends on the junction temperature T<sub>j</sub>. Higher power dissipation is allowed in conjunction with lower ambient temperatures. The conditions to determine the specified values are T<sub>amb</sub> = 85 °C and the use of a two layer PCB.

## 9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
$V_I$	input voltage		1.1	3.6	V
$T_{amb}$	ambient temperature		-40	+85	°C

## 10. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient		[1][2] 130	K/W

- [1] The overall  $R_{th(j-a)}$  can vary depending on the board layout. To minimize the effective  $R_{th(j-a)}$ , all pins must have a solid connection to larger Cu layer areas e.g. to the power and ground layer. In multi-layer PCB applications, the second layer should be used to create a large heat spreader area right below the device. If this layer is either ground or power, it should be connected with several vias to the top layer connecting to the device ground or supply. Try not to use any solder-stop varnish under the chip.
- [2] Rely on the measurement data given for a rough estimation of the  $R_{th(j-a)}$  in the application. The actual  $R_{th(j-a)}$  value may vary in applications using different layer stacks and layouts.

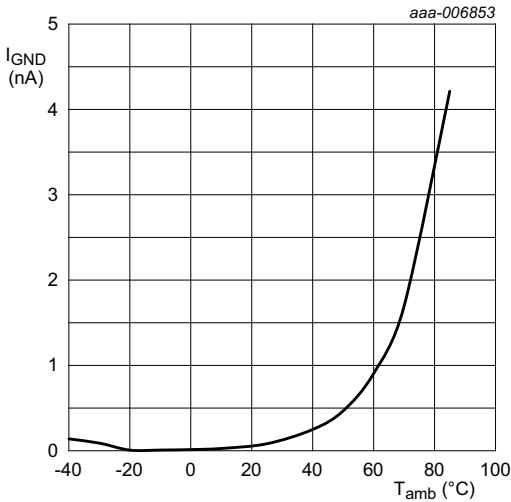
## 11. Static characteristics

Table 8. Static characteristics

$V_{I(VIN)} = 0.9\text{ V to }3.6\text{ V}$ , unless otherwise specified; Voltages are referenced to GND (ground = 0 V).

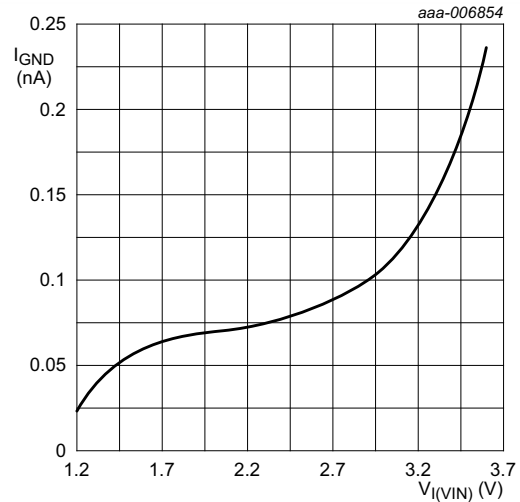
Symbol	Parameter	Conditions	$T_{amb} = 25\text{ °C}$			$T_{amb} = -40\text{ °C to }+85\text{ °C}$		Unit
			Min	Typ	Max	Min	Max	
$V_{IH}$	HIGH-level input voltage	EN input						
		$V_{I(VIN)} = 1.1\text{ V to }1.3\text{ V}$	-	-	-	1.0	-	V
		$V_{I(VIN)} = 1.3\text{ V to }1.8\text{ V}$	-	-	-	1.2	-	V
		$V_{I(VIN)} = 1.8\text{ V to }3.6\text{ V}$	-	-	-	1.2	-	V
$V_{IL}$	LOW-level input voltage	EN input						
		$V_{I(VIN)} = 1.1\text{ V to }1.3\text{ V}$	-	-	-	-	0.3	V
		$V_{I(VIN)} = 1.3\text{ V to }1.8\text{ V}$	-	-	-	-	0.4	V
		$V_{I(VIN)} = 1.8\text{ V to }3.6\text{ V}$	-	-	-	-	0.45	V
$I_I$	input leakage current	$V_{I(EN)} = 0\text{ V or }3.6\text{ V}$	-	0.1	-	-	500	nA
$I_{GND}$	ground current	$V_{I(EN)} = 0\text{ V or }3.6\text{ V}$ ; VOUT open; see <a href="#">Figure 5</a> and <a href="#">Figure 6</a>	-	-	-	-2	-	μA
$I_{S(OFF)}$	OFF-state leakage current	$V_{I(VIN)} = 3.6\text{ V}$ ; $V_{I(EN)} = \text{GND}$ ; $V_{I(VOUT)} = \text{GND}$ ; see <a href="#">Figure 8</a>	-	10	-	-	600	nA
$R_{dch}$	discharge resistance	VOUT output; $V_{I(VIN)} = 3.3\text{ V}$	-	90	-	-	120	Ω

11.1 Graphs



$V_{I(VIN)} = 1.8 \text{ V}; V_{I(EN)} = 1.8 \text{ V}; I_{LOAD} = 500 \text{ mA}.$

Fig 5. Ground current versus temperature



$V_{I(EN)} = V_{I(VIN)}; T_{amb} = 25 \text{ °C}; I_{LOAD} = 500 \text{ mA}.$

Fig 6. Ground current versus input voltage on pin VIN

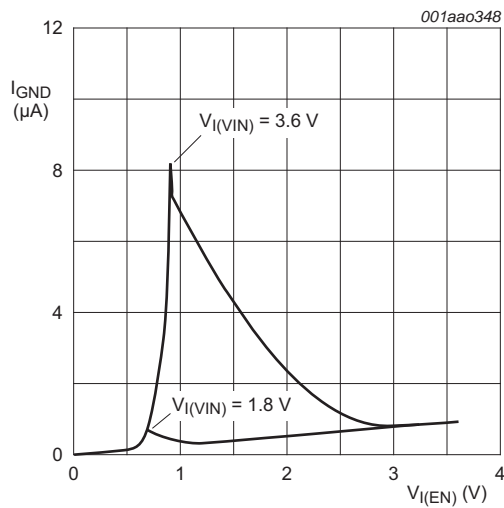
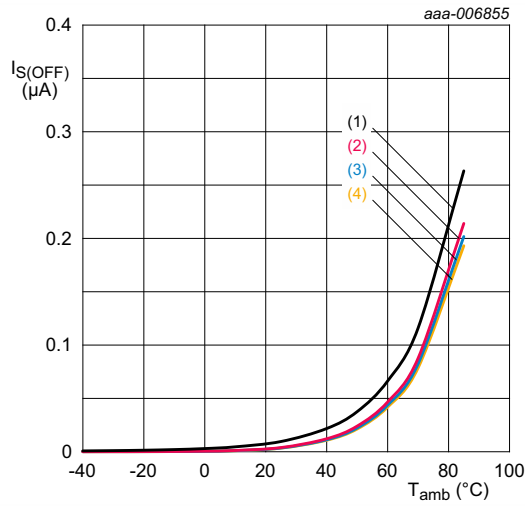


Fig 7. Additional ground current versus input voltage



- $V_{I(EN)} = \text{GND}$ .
- (1)  $V_{I(VIN)} = 3.6 \text{ V}$ .
  - (2)  $V_{I(VIN)} = 2.5 \text{ V}$ .
  - (3)  $V_{I(VIN)} = 1.8 \text{ V}$ .
  - (4)  $V_{I(VIN)} = 1.2 \text{ V}$ .

**Fig 8. OFF-state leakage current versus temperature**

## 11.2 ON resistance

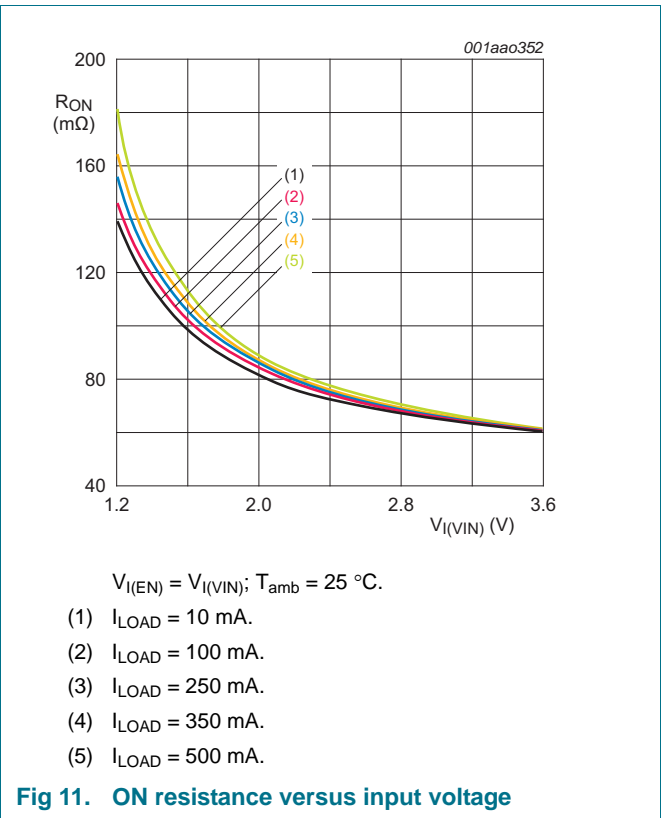
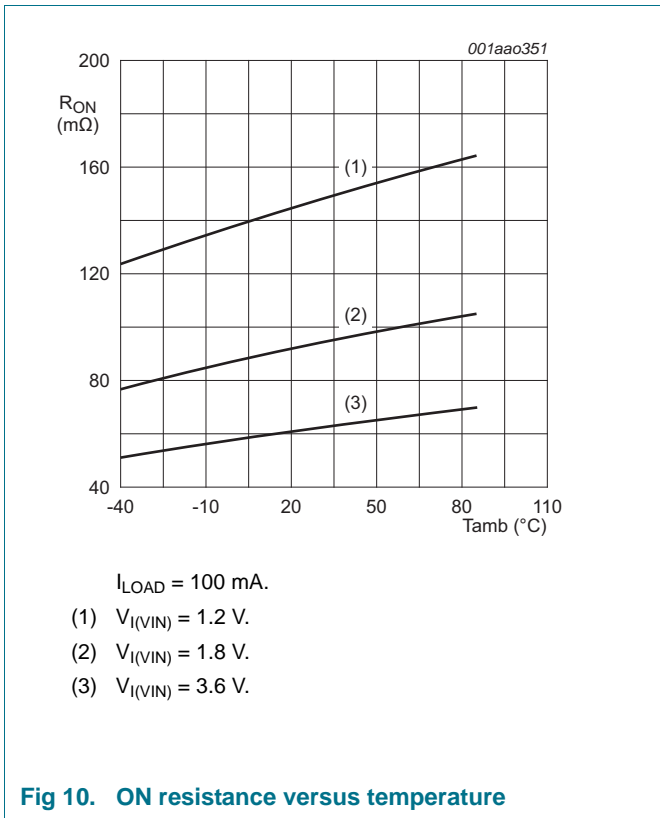
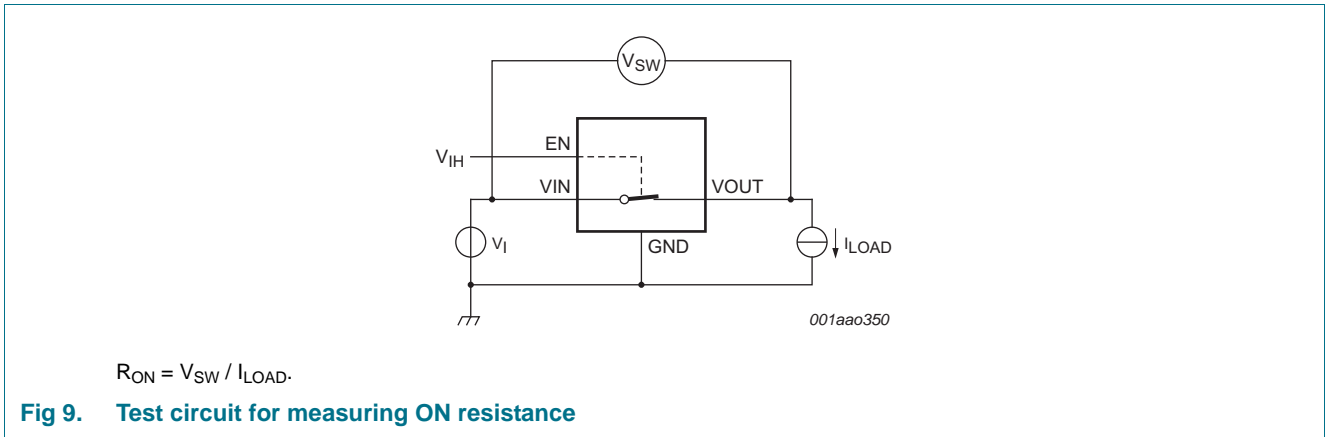
**Table 9. ON resistance**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	$T_{\text{amb}} = -40 \text{ }^\circ\text{C to } +85 \text{ }^\circ\text{C}$			Unit
			Min	Typ <sup>[1]</sup>	Max	
$R_{\text{ON}}$	ON resistance	$V_{I(EN)} = 1.5 \text{ V}; I_{\text{LOAD}} = 200 \text{ mA};$ see <a href="#">Figure 9</a> , <a href="#">Figure 10</a> and <a href="#">Figure 11</a>				
		$V_{I(VIN)} = 1.2 \text{ V}$	-	150	-	mΩ
		$V_{I(VIN)} = 1.5 \text{ V}$	-	110	-	mΩ
		$V_{I(VIN)} = 1.8 \text{ V}$	-	95	130	mΩ
		$V_{I(VIN)} = 2.5 \text{ V}$	-	75	-	mΩ
		$V_{I(VIN)} = 3.6 \text{ V}$	-	65	-	mΩ

[1] Typical values are measured at  $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ .

11.3 ON resistance test circuit and waveforms



## 12. Dynamic characteristics

**Table 10. Dynamic characteristics**

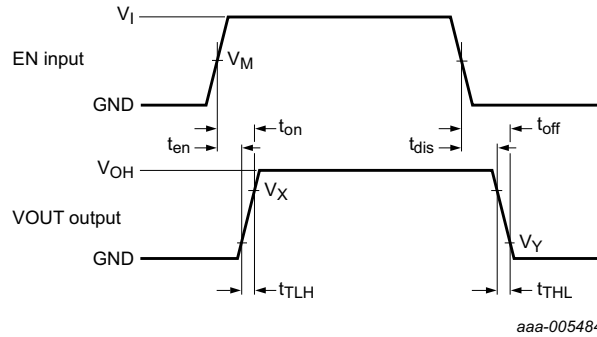
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 12](#) and [Figure 13](#).

Symbol	Parameter	Conditions	T <sub>amb</sub> = -40 °C to +85 °C			Unit
			Min	Typ <sup>[1]</sup>	Max	
t <sub>en</sub>	enable time	EN to VOUT; see <a href="#">Figure 14</a>				
		V <sub>I(VIN)</sub> = 1.8 V	175	310	-	μs
		V <sub>I(VIN)</sub> = 3.3 V	80	135	-	μs
t <sub>dis</sub>	disable time	EN to VOUT; see <a href="#">Figure 14</a>				
		V <sub>I(VIN)</sub> = 1.8 V	-	10	-	μs
		V <sub>I(VIN)</sub> = 3.3 V	-	8	-	μs
t <sub>on</sub>	turn-on time	EN to VOUT; see <a href="#">Figure 14</a> and <a href="#">Figure 15</a>				
		V <sub>I(VIN)</sub> = 1.8 V	285	570	-	μs
		V <sub>I(VIN)</sub> = 3.3 V	150	280	-	μs
t <sub>off</sub>	turn-off time	EN to VOUT; see <a href="#">Figure 16</a> and <a href="#">Figure 17</a>				
		V <sub>I(VIN)</sub> = 1.8 V	-	200	-	μs
		V <sub>I(VIN)</sub> = 3.3 V	-	180	-	μs
t <sub>TLH</sub>	LOW to HIGH output transition time	VOUT				
		V <sub>I(VIN)</sub> = 1.8 V	110	265	-	μs
		V <sub>I(VIN)</sub> = 3.3 V	70	150	-	μs
t <sub>THL</sub>	HIGH to LOW output transition time	VOUT				
		V <sub>I(VIN)</sub> = 1.8 V	-	190	-	μs
		V <sub>I(VIN)</sub> = 3.3 V	-	172	-	μs

[1] Typical values are measured at T<sub>amb</sub> = 25 °C.



12.1 Waveforms and test circuits



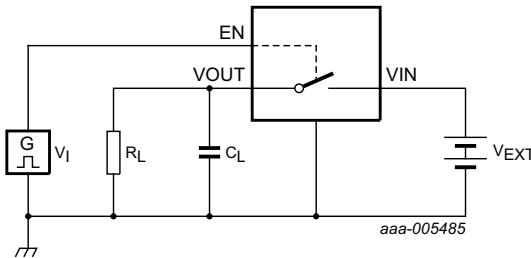
Measurement points are given in [Table 11](#).

Logic level:  $V_{OH}$  is the typical output voltage that occurs with the output load.

Fig 12. Switching times

Table 11. Measurement points

Supply voltage	EN Input		Output		
$V_{I(VIN)}$	$V_M$	$t_r, t_f$	$V_M$	$V_X$	$V_Y$
1.1 V to 3.6 V	$0.5 \times V_{I(EN)}$	$\leq 100$ ns	$0.5 \times V_{OH}$	$0.9 \times V_{OH}$	$0.1 \times V_{OH}$



Test data is given in [Table 12](#).

Definitions test circuit:

$R_L$  = Load resistance.

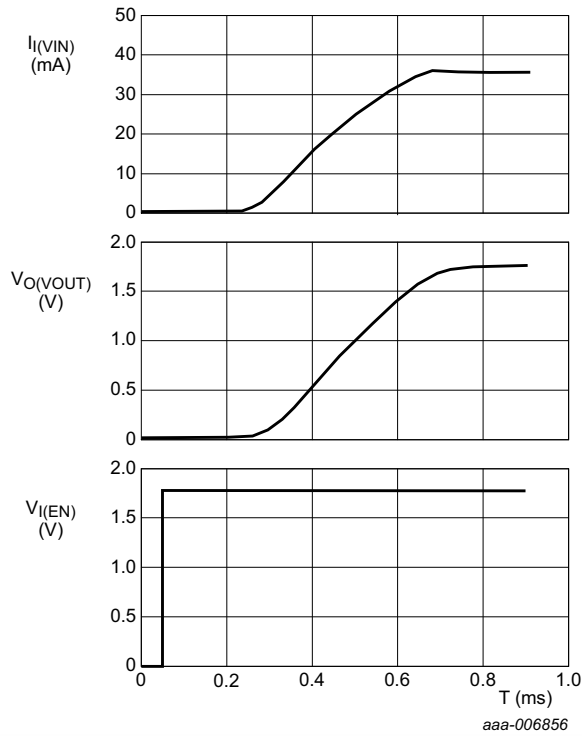
$C_L$  = Load capacitance including jig and probe capacitance.

$V_{EXT}$  = External voltage for measuring switching times.

Fig 13. Test circuit for measuring switching times

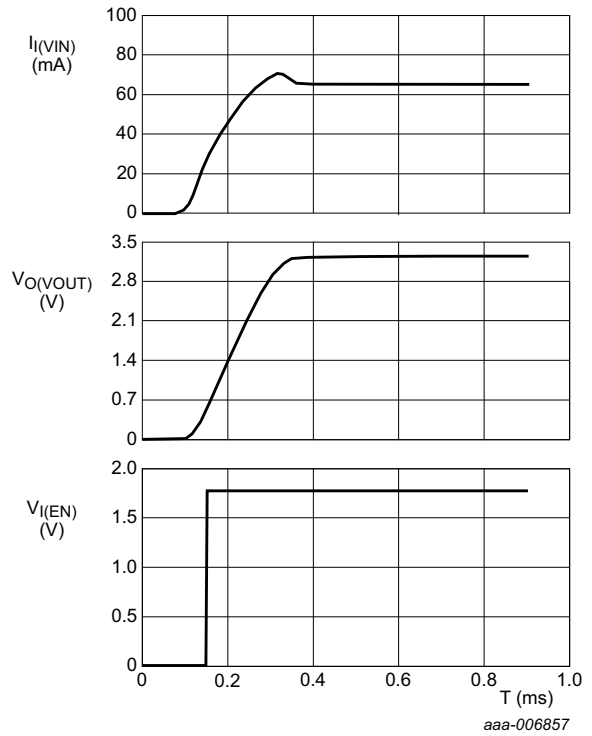
Table 12. Test data

Supply voltage	EN Input	Load	
$V_{EXT}$	$V_{I(EN)}$	$C_L$	$R_L$
1.1 V to 3.6 V	1.8 V	1 $\mu$ F	500 $\Omega$



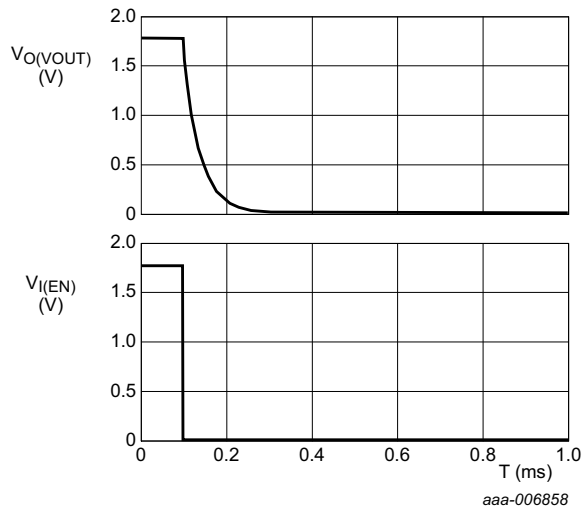
$V_{I(VIN)} = 1.8\text{ V}; V_{I(EN)} = 1.8\text{ V}; R_L = 50\ \Omega; C_L = 1\ \mu\text{F}.$

**Fig 14. Turn-on time**



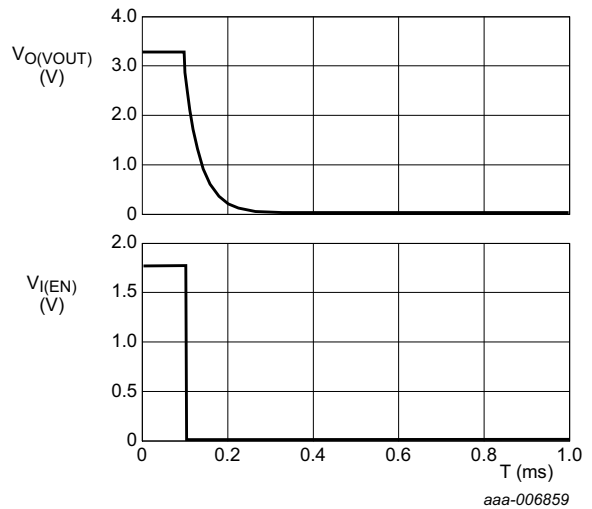
$V_{I(VIN)} = 3.3\text{ V}; V_{I(EN)} = 1.8\text{ V}; R_L = 50\ \Omega; C_L = 1\ \mu\text{F}.$

**Fig 15. Turn-on time**



$V_{I(VIN)} = 1.8\text{ V}; V_{I(EN)} = 1.8\text{ V}; R_L = 50\ \Omega; C_L = 1\ \mu\text{F}.$

**Fig 16. Turn-off time**



$V_{I(VIN)} = 3.3\text{ V}; V_{I(EN)} = 1.8\text{ V}; R_L = 50\ \Omega; C_L = 1\ \mu\text{F}.$

**Fig 17. Turn-off time**

### 13. Package outline

WLCSP4: wafer level chip-scale package; 4 bumps; 0.77 x 0.77 x 0.51 mm (Backside coating included)

NX3P2902B

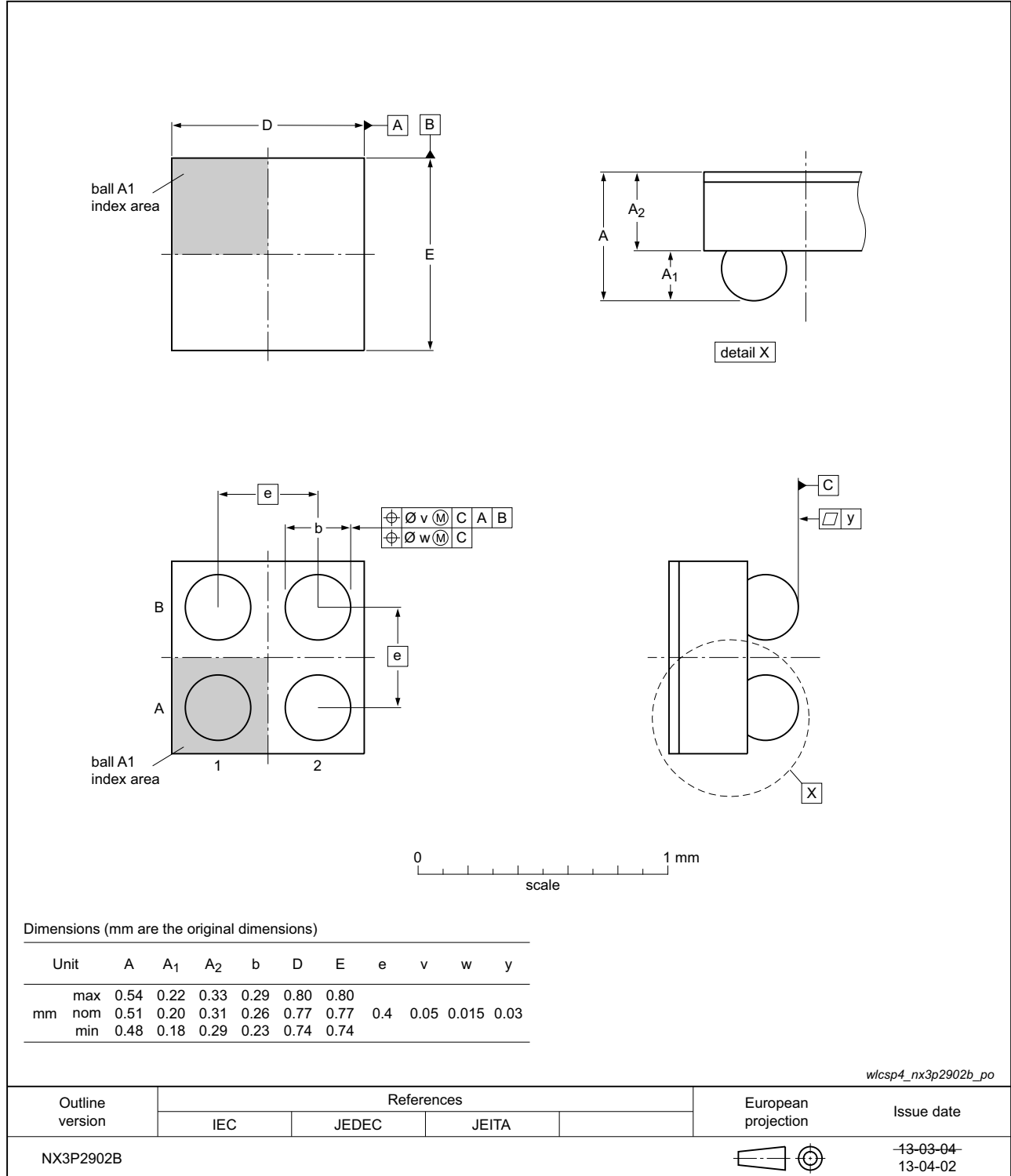


Fig 18. Package outline WLCSP4 (NX3P2902B)

## 14. Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
ESD	ElectroStatic Discharge
HBM	Human Body Model
MOSFET	Metal-Oxide Semiconductor Field Effect Transistor

## 15. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3P2902B v.2	20180222	Product data sheet	-	NX3P2902B v.1.1
Modifications:	<ul style="list-style-type: none"> <li>Updated <a href="#">Section 4 "Ordering information"</a></li> </ul>			
NX3P2902B v.1.1	20161101	Product data sheet	-	NX3P2902B v.1
Modifications:	<ul style="list-style-type: none"> <li><a href="#">Table 8</a>: Updated OFF-state current specification</li> </ul>			
NX3P2902B v.1	20130429	Product data sheet	-	-

## 16. Legal information

### 16.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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For sales office addresses, please send an email to: [salesaddresses@nxp.com](mailto:salesaddresses@nxp.com)

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